

# NCE N-Channel Enhancement Mode Power MOSFET

### Description

The NCE01H11 uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

## **General Features**

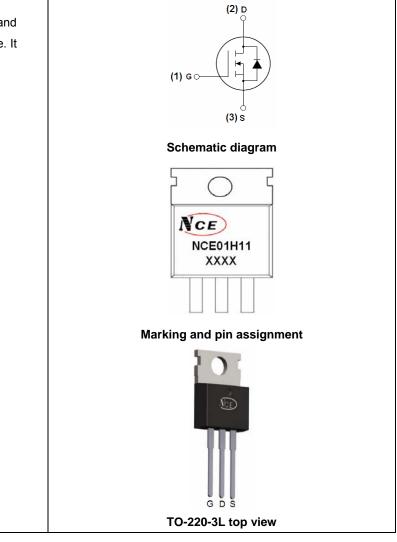
- V<sub>DS</sub> =100V,I<sub>D</sub> =110A
  R<sub>DS(ON)</sub>=6.8mΩ (typical) @ V<sub>GS</sub>=10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAs
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

### Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



## Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE01H11	NCE01H11	TO-220-3L	-	-	-

#### Absolute Maximum Ratings (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	100	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous (Silicon Limited)	Ι <sub>D</sub>	110	А
Drain Current-Continuous (Package Limited)	Ι <sub>D</sub>	110	А
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	78	А
Pulsed Drain Current	I <sub>DM</sub>	440	А
Maximum Power Dissipation	PD	220	W
Derating factor		1.47	W/°C



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# NCE01H11

Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	1100	mJ
Parameter	Symbol	Limit	Unit
Operating Junction and Storage Temperature Range	TJ,T <sub>STG</sub>	-55 To 175	°C

## **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	R <sub>θJC</sub>	0.68	°C/W

## Electrical Characteristics (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	ameter Symbol Condition		Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	100	113	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)		·				
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	2	3	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =40A	-	6.8	8	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =25V,I <sub>D</sub> =57A	90	-	-	S
Dynamic Characteristics (Note4)		·				
Input Capacitance	Clss		-	6500	-	PF
Output Capacitance	Coss	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V, F=1.0MHz	-	380	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>		-	330	-	PF
Switching Characteristics (Note 4)		·		•		
Turn-on Delay Time	t <sub>d(on)</sub>		-	26	-	nS
Turn-on Rise Time	tr	$V_{DD}$ =30V, $I_D$ =2A, $R_L$ =15 $\Omega$	-	24	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>GS</sub> =10V,R <sub>G</sub> =2.5Ω	-	91	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	39	-	nS
Total Gate Charge	Qg	)/ _20)// _20A	-	163		nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =30V,I <sub>D</sub> =30A, V <sub>GS</sub> =10V	-	31		nC
Gate-Drain Charge	Q <sub>gd</sub>	v <sub>GS</sub> -10v	-	64		nC
Drain-Source Diode Characteristics		·		•		
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =40A	-		1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	110	А
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 40A	-	42		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	66		nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t  $\leq$  10 sec.

3. Pulse Test: Pulse Width ≤ 300 $\mu$ s, Duty Cycle ≤ 2%.





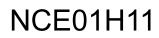


4. Guaranteed by design, not subject to production 5. EAS condition : Tj=25 $^\circ C,V_{DD}$ =50V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$ 

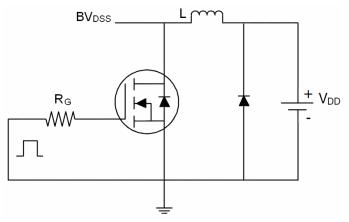


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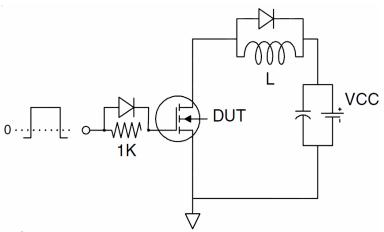




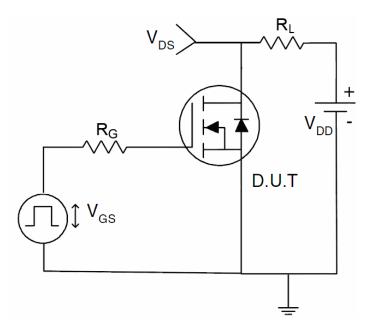
## Test Circuit 1) E<sub>AS</sub> test Circuit



## 2) Gate charge test Circuit



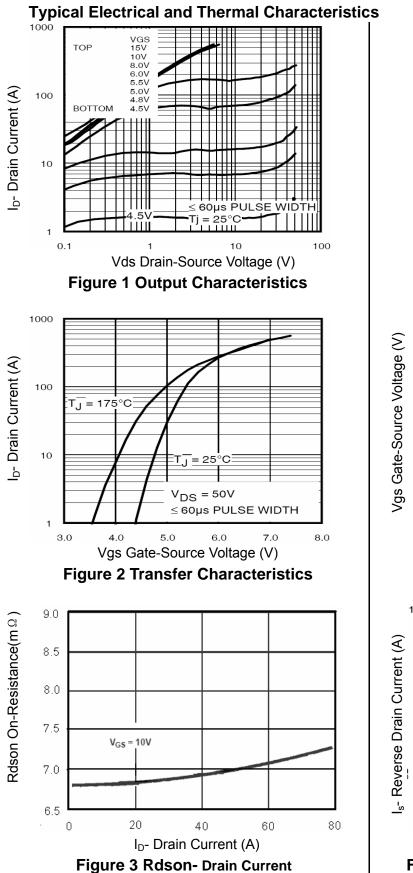
3) Switch Time Test Circuit







NCE01H11



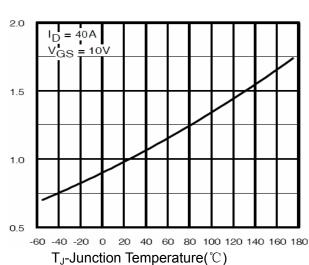
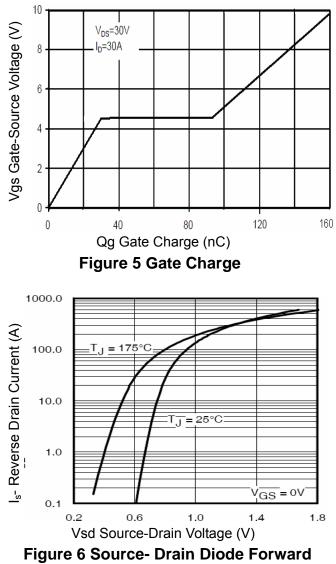


Figure 4 Rdson-JunctionTemperature







100

V<sub>DS</sub>=V<sub>GS</sub>

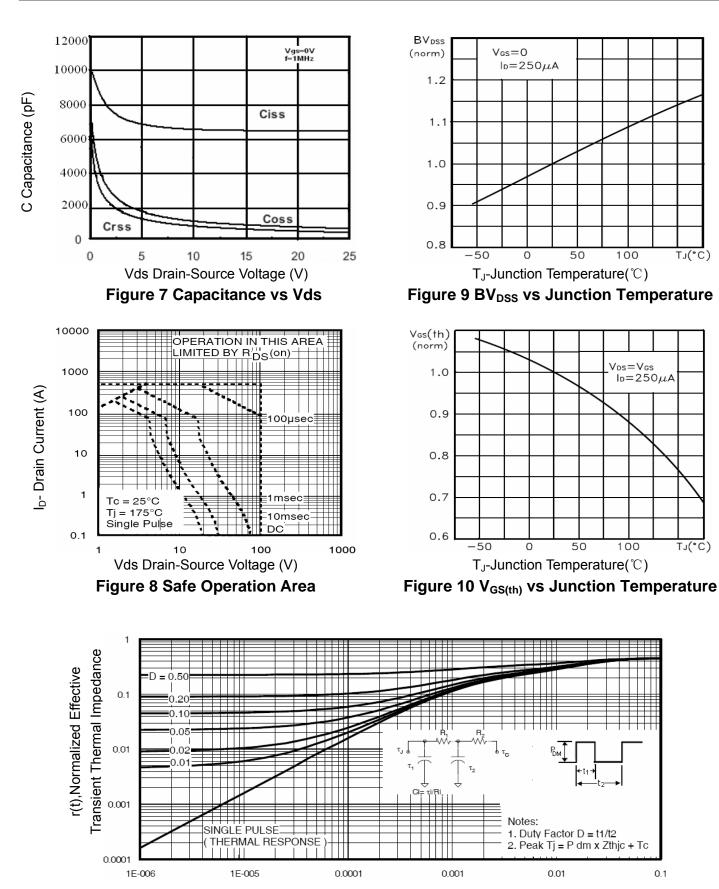
100

I₀=250µA

TJ(°C)

TJ(°C)





Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance

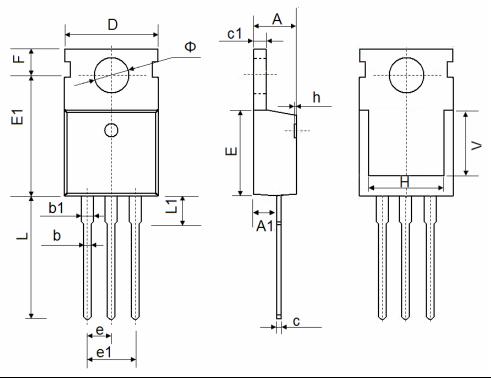
0.1



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## TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimension	s In Inches		
Symbol	Min.	Max.	Min.	Max.		
А	4.400	4.600	0.173	0.181		
A1	2.250	2.550	0.089	0.100		
b	0.710	0.910	0.028	0.036		
b1	1.170	1.370	0.046	0.054		
С	0.330	0.650	0.013	0.026		
c1	1.200	1.400	0.047	0.055		
D	9.910	10.250	0.390	0.404		
E	8.9500	9.750	0.352	0.384		
E1	12.650	12.950	0.498	0.510		
е	2.54	0 TYP.	0.100	0.100 TYP.		
e1	4.980	5.180	0.196	0.204		
F	2.650	2.950	0.104	0.116		
Н	7.900	8.100	0.311	0.319		
h	0.000	0.300	0.000	0.012		
L	12.900	13.400	0.508	0.528		
L1	2.850	3.250	0.112	0.128		
V	7.50	0 REF.	0.295	REF.		
Ф	3.400	3.800	0.134	0.150		







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